

July 2008

2SC5242/FJA4313 **NPN** Epitaxial Silicon Transistor

Applications

- · High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

- High Current Capability: I_C = 15A
 High Power Dissipation : 120......
- High Frequency: 30MHz.
- High Voltage : V_{CEO}=230V
- Wide S.O.A for reliable operation.
- · Excellent Gain Linearity for low THD.
- Complement to 2SA1962/FJA4213.
- Thermal and electrical Spice models are available
- Same transistor is also available in:
 - --TO264 package, 2SC5200/FJL4315: 150 watts
 - --TO220 package, FJP5200: 80 watts
 - --TO220F package, FJPF5200 : 50 watts



1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings* Ta = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
BV _{CBO}	Collector-Base Voltage	230	V	
BV _{CEO}	Collector-Emitter Voltage	230	75 V	
BV _{EBO}	Emitter-Base Voltage	5	V	
I _C	Collector Current(DC)	15	А	
I _B	Base Current		А	
P _D Total Device Dissipation(T _C =25°C) Derate above 25°C		130 1.04	W/°C	
T _J , T _{STG}	Junction and Storage Temperature	- 50 ~ +150	°C	

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics* Ta=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case	0.96	°C/W

^{*} Device mounted on minimum pad size

h_{FF} Classification

Classification	R	0
h _{FE1}	55 ~ 110	80 ~ 160

$\textbf{Electrical Characteristics*} \ \, \textbf{T}_{a}\text{=-}25^{\circ}\text{C unless otherwise noted}$

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =5mA, I _E =0	230			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, R _{BE} =∞	230			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =5mA, I _C =0	5			V
I _{CBO}	Collector Cut-off Current	V_{CB} =230V, I_{E} =0			5.0	μА
I _{EBO}	Emitter Cut-off Current	V _{EB} =5V, I _C =0			5.0	μА
h _{FE1}	DC Current Gain	V _{CE} =5V, I _C =1A	55		160	
h _{FE2}	DC Current Gain	V _{CE} =5V, I _C =7A	35	60		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =8A, I _B =0.8A		0.4	3.0	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =5V, I _C =7A		1.0	1.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =5V, I _C =1A		30		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, f=1MHz		200		pF

^{*} Pulse Test: Pulse Width=20μs, Duty Cycle≤2%

Ordering Information

Part Number	Marking	Package	Packing Method	Remarks
2SC5242RTU	C5242R	TO-3P	TUBE	hFE1 R grade
2SC5242OTU	C5242O	TO-3P	TUBE	hFE1 O grade
FJA4313RTU	J4313R	TO-3P	TUBE	hFE1 R grade
FJA4313OTU	J4313O	TO-3P	TUBE	hFE1 O grade

Typical Characteristics

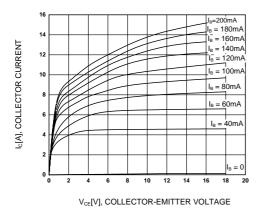


Figure 1. Static Characteristic

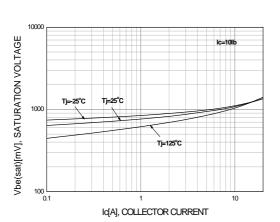


Figure 3. Base-Emitter Saturation Voltage

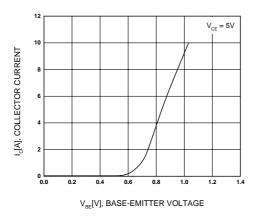


Figure 5. Base-Emitter On Voltage



Figure 2. DC current Gain

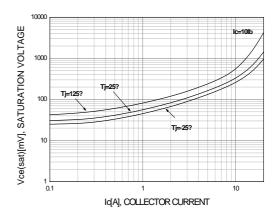


Figure 4. Collector-Emitter Saturation Voltage

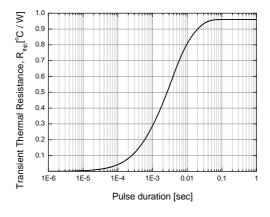


Figure 6. Thermal Resistance

Typical Characteristics

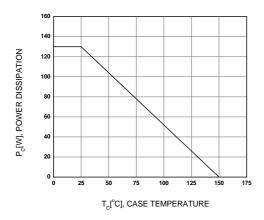


Figure 7. Power Derating

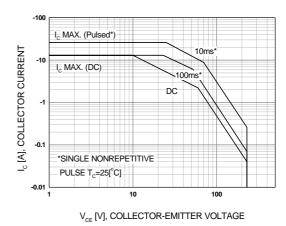
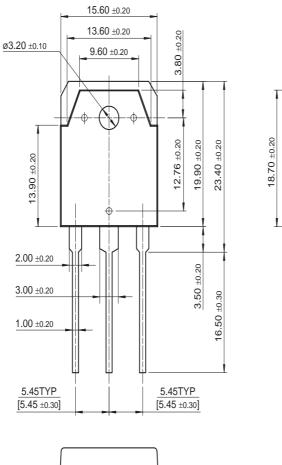
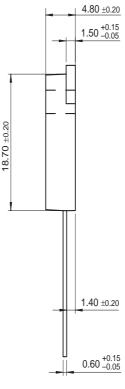


Figure 8. Safe Operating Area

Package Dimensions

TO-3P





Dimensions in Millimeters





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